

#### 2.0x1.25mm SMD CHIP LED LAMP

PRELIMINARY SPEC

Part Number: KPHCM-2012EC-T

HIGH EFFICIENCY RED

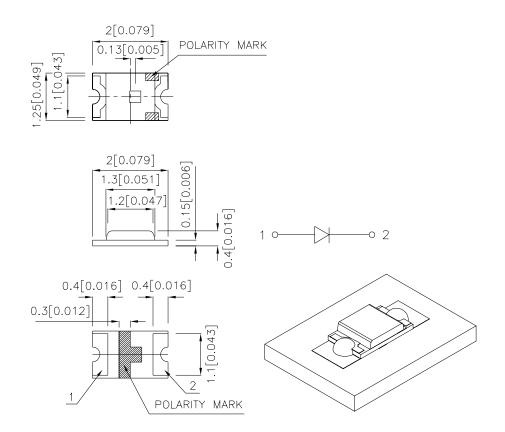
#### **Features**

- •2.0X1.25mm SMT LED.0.5mm MAX.THICKNESS.
- •LOW POWER CONSUMPTION.
- •WIDE VIEWING ANGLE.
- •IDEAL FOR BACKLIGHT AND INDICATOR.
- •VARIOUS COLORS AND LENS TYPES AVAILABLE.
- •PACKAGE: 2000PCS/REEL.
- •MOISTURE SENSITIVITY LEVEL : LEVEL 3.
- •RoHS COMPLIANT.

#### **Description**

The High Efficiency Red source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode.

# **Package Dimensions**



#### Notes:

- All dimensions are in millimeters (inches).
- All differsions are infillimeters (inches).
   Tolerance is ±0.1(0.004") unless otherwise noted.
   Specifications are subject to change without notice.
- 4. The device has a single mounting surface. The device must be mounted according to the specifications.





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### **Selection Guide**

Part No.	Dice	Lens Type	Iv (mcd) [2] @ 20mA		Viewing Angle [1]
			Min.	Тур.	201/2
KPHCM-2012EC-T	HIGH EFFICIENCY RED(GaAsP/GaP)	WATER CLEAR	7	20	110°

1.  $\theta$ 1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value. 2.Luminous Intensity / Luminous Flux: +/-15%.

### Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	High Efficiency Red	627		nm	IF=20mA
λD [1]	Dominant Wavelength	High Efficiency Red	625		nm	IF=20mA
Δλ1/2	Spectral Line Half-width	High Efficiency Red	45		nm	IF=20mA
С	Capacitance	High Efficiency Red	15		pF	VF=0V;f=1MHz
VF [2]	Forward Voltage	High Efficiency Red	2.0	2.5	V	IF=20mA
IR	Reverse Current	High Efficiency Red		10	uA	VR = 5V

### Notes:

- 1. Wavelength: +/-1nm.
- 2. Forward Voltage: +/-0.1V.

# Absolute Maximum Ratings at Ta=25°C

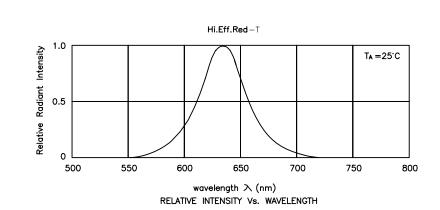
Parameter	High Efficiency Red	Units
Power dissipation	75	mW
DC Forward Current	30	mA
Peak Forward Current [1]	160	mA
Reverse Voltage	5	V
Operating / Storage Temperature	-40°C To +85°C	

# Note:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.

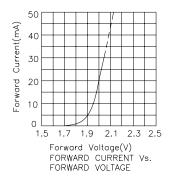
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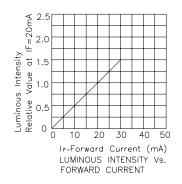
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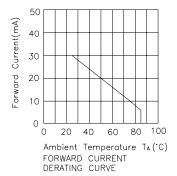


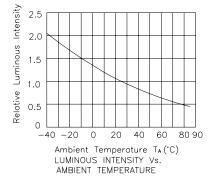
**High Efficiency Red** 

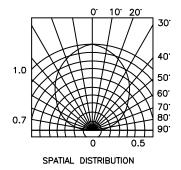
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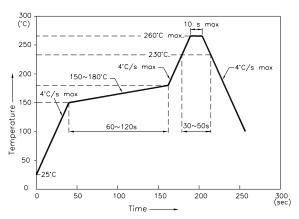


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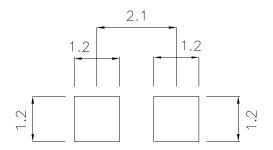
Reflow Soldering Profile For Lead-free SMT Process.



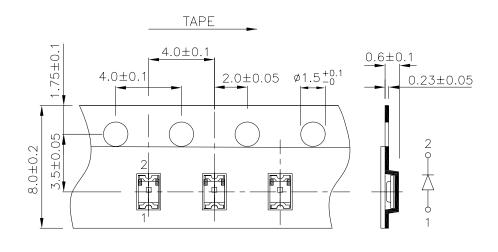
- NOTES:

  1. We recommend the reflow temperature 245°C(+/-5°C). The maximum soldering temperature should be limited to 260°C.
  - 2.Don't cause stress to the epoxy resin while it is exposed to high temperature.
  - 3. Number of reflow process shall be 2 times or less.

# **Recommended Soldering Pattern** (Units: mm; Tolerance: ±0.1)



# **Tape Specifications** (Units: mm)



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